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Superconducting proximity effect in a topological insulator using Fe(Te,Se)

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Abstract

Interest in the superconducting proximity effect has recently been reignited by theoretical predictions that it could be used to achieve topological superconductivity. Low- T_c superconductors have predominantly been used in this effort, but small energy scales of ~1 meV have hindered the characterization of the emergent electronic phase, limiting it to extremely low temperatures. In this work, we use molecular beam epitaxy to grow topological insulator Bi₂Te₃ in a range of thicknesses on top of a high- T_c superconductor Fe(Te,Se). Using scanning tunneling microscopy and spectroscopy, we detect Δ_{ind} as high as ~3.5 meV, which is the largest reported gap induced by proximity to an *s*-wave superconductor to-date. We find that Δ_{ind} decays with Bi₂Te₃ thickness, but remains finite even after the topological surface states had been formed. Finally, by imaging the scattering and interference of surface state due to Cooper pairing. Our results establish Fe-based high- T_c superconductors as a promising new platform for realizing high- T_c topological superconductivity.

When a superconductor (SC) is brought into contact with a non-superconducting (normal) material, Cooper pairs from the SC can diffuse into the normal material, which in turn becomes superconducting. This phenomenon, known as the superconducting proximity effect (SPE), has been discovered around the middle of the last century [1]. Recently, with the realization of new classes of materials such as graphene [2, 3] and Z₂ topological insulators (TIs) [4], the interest in SPE has been reignited, attracting a lot of attention from both fundamental and applications perspectives due to the novel phenomena theoretically predicted to be realized based on this effect. For example, proximity-induced superconducting p-n junctions are expected to exhibit superluminescence [5] applicable in optoelectronic devices, while heterostructures of TIs and SCs are predicted to harbor topological superconductivity hosting Majorana modes inside vortex cores [6].

The quest for achieving topological superconductivity in TI/SC heterostructures has mostly focused on coupling TIs with low- T_c SCs (NbSe₂ [7–11] and elemental SCs [12, 13]) or with a high-T_c cuprate Bi₂Sr₂CaCu₂O_{8+x} (Bi-2212) [14–17]. Although TI/NbSe₂ platform has led to a widely accepted observation of proximity-induced superconductivity in TIs [7–11], the induced superconducting gap of ~1 meV makes experimental characterization of the emergent phase challenging and limits potential future applications of any Majorana modes detected. Optimally-doped cuprate Bi-2212 exhibits a high T_c of ~91 K and a d-wave superconducting gap of ~40 meV [18], but the detection of the proximity induced superconductivity in the TIs by coupling to it has given conflicting results [14–17]. This has been attributed to the very short coherence length of Bi-2212 along the c-axis [14] and/or the large momentum-space mismatch between the Fermi surface of TI Bi₂(Se,Te)₃ near the Brillouin zone (BZ) center and that of Bi-2212 near the BZ edge [14, 15]. If the hypothesis that Fermi surface matching at the interface actually played an essential role, many Fe-based high- T_c SCs with Fermi surface pockets near the BZ center [19] could be a promising alternative for achieving high- T_c SPE in TIs. Moreover, these SCs can achieve extraordinary high superconducting gap [20], T_c [21] and upper critical fields [19]. However, in spite of immense potential, there is still no evidence to suggest that Febased high- T_c SCs could be used to induce a large gap superconductivity in a proximate nonsuperconducting TI.

In this work, we report the first observation of superconductivity at the surface of a prototypical topological insulator Bi_2Te_3 in proximity to an Fe-based high- T_c SC Fe(Te,Se). To create the desired interface, we deposit a thin film of Bi_2Te_3 using molecular-beam epitaxy (MBE) on top of a cleaved FeTe_{1-x}Se_x (x = 0.45, $T_c \sim 14.5$ K) bulk single crystal (Fig. 1a, Methods). We study Bi_2Te_3 films in a range of thicknesses: 1 quintuple layer (QL), 3 QLs and 5 QLs, which span the regimes before and after the Dirac node is formed [22]. One of the main challenges in successful Bi_2Te_3 /Fe(Te,Se) heterostructure growth is the incompatible atomic surface structure of the two materials – Fe(Te,Se) typically cleaves along the (001) orientation to expose a square lattice of Se/Te atoms (Fig. 1d), while Bi_2Te_3 has a surface lattice structure with hexagonal symmetry (Fig. 1e). This often results in the formation of two types of Bi_2Te_3 film domains rotated in-plane by 30 degrees with respect to one another (Fig. 1b and Ref. [34]). However, these domains are large enough that we can easily locate single-domain ~50-100 nm square regions of the sample using scanning tunneling microscopy (STM) (Fig. 2).

To realize topological superconductivity in TI/SC heterostructures, two main conditions need to be satisfied: the existence of helical Dirac states on the surface of a TI and a gap in these states due to induced s-wave superconducting pairing. First, we characterize the largescale electronic structure of our films by using quasiparticle interference (QPI) imaging. This commonly used spectroscopic method relies on elastic scattering of electrons on the surface of a material that can be visualized as "waves" in STM dl/dV images [23]. For each of the 3 heterostructures studied in this work, we acquire a series of dI/dV maps over a large square region of the Bi₂Te₃ surface, and examine their Fourier transforms (FTs) as a function of energy (Fig. 2). Based on the thickness-dependent angle-resolved photoemission spectroscopy (ARPES) measurements, Bi₂Te₃ films thicker than 2 QLs are expected to be in the regime where the top and the bottom surface do not hybridize [22], and their topological surface state (SS) band structure consists of a single Dirac cone located at Γ . Although backscattering is prohibited in ideal topological insulators, small hexagonal warping of the constant energy contour away from the Dirac point has been shown to open a scattering channel along the Γ -M direction [24–26]. On the surface of our Bi₂Te₃ films of 3 QL (Fig. 2(e-g)) and 5 QL (Fig. 2(i-k)) thickness, we indeed observe the characteristic angle-dependent QPI pattern with energy-dispersive wave vectors

along the F-M direction. This is consistent with the previous experiments on cleaved Bi₂Te₃ single crystals [24, 25] and films [26], and allows us to visualize the topological SS band dispersion (Fig. 2h,I). QPI measurements of 1 QL Bi₂Te₃ film also reveal a dispersive QPI pattern in a wide range of energies studied. However, QPI morphology appears to be more isotropic with similar intensity along all angles (Fig. 2c and Ref. [34]). This signature is likely a consequence of low spin-momentum locking indicative of degenerate nature of the SS in 1 QL Bi₂Te₃ [9], which facilitates the observation of the backscattering vector. We note that the observed SS in 1 QL Bi₂Te₃ is clearly distinct from the recently reported SS on the surface of Fe(Te,Se) [27], which has the Dirac point located 4.4 meV below the Fermi level and ~5 times smaller Fermi wavevector k_f . We also emphasize that this is the first QPI imaging of the Bi₂Te₃ SS in a range of thicknesses down to the single QL. Importantly, the extracted dispersions match well with the previous ARPES measurements [9] (Fig. 2d,h,I), and as such confirm the expected large-scale electronic structure of our Bi₂Te₃ films.

We proceed to look for signatures of the induced superconductivity at the surface of Bi_2Te_3 and start with the 1QL $Bi_2Te_3/Fe(Te,Se)$ heterostructure. This thickness should in principle maximize the magnitude of the induced superconducting gap at the TI surface, which is expected to decrease away from the interface [28]. Typical dl/dV spectrum at the surface of our Bi_2Te_3 film reveals a clear energy gap $\Delta_{ind} \sim 3.5$ meV (Fig. 3a), calculated as one half of the energy difference between the two gap edge peaks. The magnitude of Δ_{ind} on Bi_2Te_3 is spatially homogeneous [34] and the same gap has been detected on multiple regions of the sample separated by large distances. It is also significantly larger than that obtained on the surface of non-superconducting, antiferromagnetic parent compound FeTe monolayer grown on Bi_2Te_3 reported to be ~1 meV [29]. The observed gap edge peaks in our dl/dV spectra are approximately symmetric with respect to the Fermi level (Fig. 3a), which is consistent with a pairing induced gap. We acquire the average dl/dV spectrum as a function of temperature over the identical region of the Bi_2Te_3 film and find that the gap persists up to T_c' of 10 K (Fig. 3a). Although T_c' is slightly lower than the bulk $T_c \sim 14.5$ K of our Fe(Te,Se) substrate, this difference can be attributed to local T_c variations suspected to occur in Fe(Te,Se) [30]. As such, these

measurements present the first indication that Δ_{ind} may be a proximity-induced superconducting gap.

To obtain further evidence of the superconducting origin of Δ_{ind} , we investigate the dependence of our *dI/dV* spectra on the applied magnetic field. For a type-II SC such as Fe(Te,Se), magnetic field will penetrate the material in quantized flux quanta below upper critical field H_{c2} in the form of vortices. If the surface of our Bi₂Te₃ film becomes superconducting due to proximity to a type-II SC, we would expect to observe Abrikosov vortices as dark regions in a *dI/dV* maps at ~ Δ_{ind} (Figs. 3b-g) that each shows a vortex lattice up to the highest magnetic field measured. From these, we calculate the average magnetic flux per vortex to be 2.16 ± 0.07 x 10⁻¹⁵ m²T [34], in good agreement with the expected single magnetic flux quantum of 2.07 x 10⁻¹⁵ m²T. The vortices in our Bi₂Te₃/Fe(Te,Se) heterostructure persist up to much larger fields compared to Bi₂Te₃/NbSe₂ [7], which is consistent with the extraordinary high H_{c2} of the Fe(Te,Se) family of materials [32]. The linecut through a vortex core shows the suppression of gap edge peaks inside the vortex (Fig. 3h), also confirming the superconducting origin of Δ_{ind} .

Next, we explore the electronic structure of thicker Bi₂Te₃ films, looking for signatures of the induced superconducting gap Δ_{ind} . For each sample, we acquire dl/dV spectra under similar conditions, which all show a prominent gap in the density-of-states (Fig. 4a). Similarly to Ref. [8], Δ_{ind} in 1 QL Bi₂Te₃ film is approximately equal to that measured on the substrate surface prior to growth (Fig. 4a). In thicker films, Δ_{ind} gets reduced as the film thickness increases, reaching ~ 1.8 meV for the 3 QL film and ~ 1.5 meV for the 5 QL Bi₂Te₃ film, which is consistent with the general trend expected from theoretical calculations [28]. The measured decay rate of Δ_{ind} in our heterostructures is also comparable to that in Bi₂Te₃/NbSe₂ system [8] (Fig. 4b). However, we emphasize that Δ_{ind} in our heterostructures is ~3 times larger than the previous largest Δ_{ind} [7–13], and presents the largest induced Δ_{ind} to-date in any Tl/s-wave SC heterostructure. We also note that none of the dl/dV spectra have a flat bottom reaching zero conductance around the Fermi level. Therefore, simple s-wave BCS function [33] cannot

reproduce the shape of our spectra [34]. Although previous experiments on $Bi_2Te_3/NbSe_2$ related similar aberration in thicker films to the emergence of topological surface states [8], we deem this unlikely as we observe this deviation even in the 1 QL thick Bi_2Te_3 film, where Dirac node is yet to be formed.

Finally, we proceed to unveil if emergent superconductivity at the surface of Bi_2Te_3 indeed leads to a gap in its SS. To accomplish this, we use QPI imaging to map the SS band crossing the Fermi level in small energy increments. If a gap in the SS exists, the FTs of *dl/dV* maps near the Fermi level should exhibit no detectable QPI signal within the gap. We again start with the 1QL Bi₂Te₃/Fe(Te,Se), where the only coherent band expected to cross the Fermi level is the SS band. At energies larger than or comparable to Δ_{ind} , Fourier transforms of *dl/dV* maps (Figs. 5a-d) exhibit a QPI pattern qualitatively similar to that observed at higher energies (Fig. 2c). However, as we enter the region within the superconducting gap, we discover a striking suppression of scattering in a range of energies from -2 meV to +2 meV, indicating a full gap in the SS around the Fermi level (Figs. 5e-i). This visual observation is further supported by a more detailed analysis of the QPI intensity as a function of energy, where complete suppression of the QPI pattern occurs exactly within Δ_{ind} and recovers outside of the gap (Fig. 5j). The suppression of QPI has also been confirmed for the 3 QL Bi₂Te₃ sample, consistent with a gap in the topological SS (Fig. 5k). Our data presents the first microscopic visualization of a full gap in the coherent SS of Bi₂Te₃ due to proximity induced pairing correlations.

One of the intriguing properties of a topological superconductor in this geometry is that each vortex on its surface is expected to host a Majorana zero mode [6]. This mode can be detected as a peak in the density-of-states at zero energy. In contrast to bound states in vortices of conventional superconductors [35], a Majorana mode should not split in energy away from the vortex center [10, 36]. This signature behavior has been observed in >3 QL thick Bi₂Te₃ films grown on NbSe₂, but is notably absent if the Bi₂Te₃ film thickness is reduced [10]. Interestingly, in our experiments, even in the 1 QL Bi₂Te₃ film in which the topological surface state is yet to be formed, we observe a zero-bias peak that gets suppressed, but does not seem to split away from the vortex center (Fig. 3h). Further experiments, using spin-polarized tunneling measurements [11], are clearly necessary to shed light on the origin of this peak and how it relates to the recently observed zero bias peak in vortices of pristine $FeTe_{0.55}Se_{0.45}$ attributed to a Majorana mode [37].

Our results highlight the promise of achieving topological superconductivity with higher Δ_{ind} and T_c using Fe(Te,Se) and related Fe-based SCs. For example, using a single layer FeSe as a substrate, which exhibits ~5 times larger superconducting gap [20] and ~8 times higher T_c [21] compared to bulk Fe(Te,Se), could pave the way towards topological superconductivity above liquid nitrogen temperatures. Our experiments could also serve to spark further theoretical work on deeper understanding of the proximity effects in multiband/orbital SCs. Finally, our observations have important implications beyond achieving topological superconductivity with enhanced metrics. Recent experiments and theory suggest that unconventional pairing can be induced at the interface of strong spin-orbit coupled materials (regardless of their topological nature) and SCs by the application of in-plane magnetic field [38]. Our work introduces a viable platform to explore this pairing tunability without the need of milliKelvin temperatures.

Methods

High quality FeTe_{1-x}Se_x bulk single crystals were grown using self-flux method, and cleaved along the (001) direction in ultra-high vacuum (UHV) to expose a clean surface free of contaminants. Bulk superconducting $T_c \sim 14.5$ K was confirmed by ex-*situ* magnetization measurements [34]. Crystalline orientation of the substrate is confirmed by the square lattice observed in STM topographs (Fig. 1d). During the growth process, RHEED pattern (obtained using a 15 keV RHEED gun manufactured by Sentys Inc) was continuously monitored to establish the quality of the substrate and the film surface. To grow Bi₂Te₃ film, we co-evaporated 99.999% pure Bismuth and 99.99% pure Tellurium from K-cells (Sentys Inc) held at 412°C and 283°C temperatures respectively. The nominal Bi:Te flux ratio used was 1:10, which was determined by using *in-situ* quartz crystal growth monitor (QCM) prior to growth. The film was grown at the rate of 7 minutes per nominally calculated QL of Bi₂Te₃. Typical post-growth RHEED pattern of our heterostructures exhibits a streaky pattern characteristic of the layer-by layer Bi₂(Se,Te)₃ MBE growth (Fig. 1b and Ref. [34]). Based on the measured step height of 0.97 \pm 0.02 nm between the film (Fig. 1e) and the substrate (Fig. 1d) we can conclude that Bi₂Te₃ in

Fig. 1c and Fig. 2a-c is exactly 1 QL thick (Fig. 1f). Larger Bi_2Te_3 thicknesses have been determined by taking into account the deposition time and the measured Bi flux.

After the growth was completed, the heterostructure was transferred from the MBE to the STM within one hour using a vacuum "suitcase" chamber held at 10⁻¹¹ Torr base pressure, which can be directly connected to either MBE or STM chambers. As such, our material is only exposed to UHV conditions during the entire process from the MBE growth to the STM measurement.

STM data was acquired using Unisoku USM1300 STM at the base temperature of 4.5 K (with the exception of temperature dependent data in Fig. 3a). All spectroscopic measurements have been taken using a standard lock-in technique at 915 Hz frequency and bias excitation varying from 0.2 mV to 10 mV as detailed in the figure captions. STM tips used were home-made chemically etched W tips annealed to bright-orange color in UHV. Tip quality has been evaluated on the surface of single crystal Cu(111) prior to performing the measurements presented in this paper. Cu(111) surface was cleaned by repeated cycles of heating and Argon sputtering in UHV before it is inserted into the STM head.

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Figures



Figure 1. (a) Schematic of $Bi_2Te_3/Fe(Te,Se)$ heterostructure. STM measurements are probing the exposed top surface of Bi_2Te_3 . (b) Typical post-growth RHEED image of the MBE-grown heterostructure showing long streaks characteristic of two-dimensional layer-by-layer growth. (c) STM topograph showing (d) the exposed Fe(Te,Se) substrate with square atomic lattice and (e) the Bi_2Te_3 film with hexagonal lattice structure. (f) Height profile taken along the dashed red line in (c) consistent with 1 QL of Bi_2Te_3 grown on top of Fe(Te,Se). STM setup condition in: (c) $I_{set} = 10 \text{ pA}$, $V_{set} = -200 \text{ mV}$; (d) $I_{set} = 30 \text{ pA}$, $V_{set} = -50 \text{ mV}$; (e) $I_{set} = 30 \text{ pA}$, $V_{set} = -50 \text{ mV}$.



Figure 2. Thickness-dependent quasiparticle interference imaging of the Bi₂Te₃ surface states. (a,e,i) Typical STM topographs, (b,f,j) large region *dl/dV* maps acquired at 50 mV, (c,g,k) their associated Fourier transforms and (d,h,l) extracted QPI dispersion along F-M direction for 1 QL, 3 QL and 5 QL thick Bi₂Te₃ films, respectively. Thick gray lines in (d,h,l) represent fit to our data based on ARPES measurements in Ref. [22], shifted upwards by (d) ~150 meV, (h) ~100 meV and (l) ~100 meV to match the QPI dispersions. This rigid band shift can be easily explained by the difference in substrate choice and possibly different impurity concentration, as the shift of the same magnitude is also observed between ARPES studies of for example 1 QL Bi₂Te₃/NbSe₂ [9] and 1QL Bi₂Te₃/Si [22]. The FTs in (g,k) have been 6-fold symmetrized to increase the signal-to-noise. STM setup condition in: (a) *I_{set}* = 80 pA, *V_{set}* = -40 mV; (b) *I_{set}* = 450 pA, *V_{set}* = -150 mV, *V_{exc}* = 10 mV (zero-to-peak); (e) *I_{set}* = 30 pA, *V_{set}* = 50 mV, *V_{exc}* = 10 mV.



Figure 3. Temperature dependence of dI/dV spectra and Abrikosov vortex lattice imaging. (a) Average dI/dV spectrum on 1 QL Bi₂Te₃ as a function of temperature, vertically offset for clarity, showing the gap closing at ~10 K. All spectra have been acquired under the same conditions over the identical 20 nm region of the sample. (b-g) dI/dV maps acquired at -3 mV bias over the region of the sample shown in Fig. 2b in a range of magnetic fields from 0.15 T to 9 T. Each dark region in (b-g) represents a single vortex, and the vortex lattice is visible up to the highest field studied. (h) Radially averaged dI/dV spectra as a function of distance from the center of the vortex (0.15 T in (b)). Zero bias peak and the suppression of coherence peaks are apparent in the vortex center (darkest blue curve). STM setup condition in: (a) $I_{set} = 60$ pA, $V_{set} = -10$ mV, $V_{exc} = 0.2$ mV; (b-g) $I_{set} = 3$ pA, $V_{set} = -3$ mV, $V_{exc} = 1.5$ mV (zero-to-peak); (h) $I_{set} = 60$ pA, $V_{set} = -10$ mV, $V_{exc} = 0.45$ mV.



Figure 4. Evolution of the induced superconducting gap Δ_{ind} with Bi₂Te₃ film thickness. (a) Average *dl/dV* spectra obtained on: Fe(Te,Se) substrate (black), 1 QL (red), 3 QL (blue) and 5 QL (green) Bi₂Te₃ film grown on superconducting Fe(Te,Se). (b) Δ_{ind} as a function of Bi₂Te₃ film thickness. Dashed line in (b) represents the decay rate of the Δ_{ind} on the surface of Bi₂Te₃ induced by NbSe₂ from Ref. [8], scaled by a multiplicative factor to match the Δ_{ind} for 1 QL in our case. STM setup condition in: (a) (black) *I*_{set} = 30 pA, *V*_{set} = 10 mV, *V*_{exc} = 0.5 mV (zero-to-peak); (red) same as Fig. 3a; (blue) *I*_{set} = 30 pA, *V*_{set} = 5 mV, *V*_{exc} = 0.4 mV (zero-to-peak).



Figure 5. Suppression of QPI within the superconducting gap. (a-i) Fourier transforms of dl/dV maps acquired over the region in Fig. 2b. While distinct quasi-circular QPI peak can be seen in (a-d), the same peak is obviously suppressed in (e-i). Normalized QPI intensity relative to the background as a function of STM bias for (j) 1 QL thick and (k) 3 QL thick Bi₂Te₃ films [34]. Position of the pink lines in (j,k) indicate the approximate energy of the observed gap peaks, while the width of the lines corresponds to thermal broadening expected at the measurement temperature. All data in (a-i) have been acquired under the same experimental conditions (0.33 GQ junction resistance with 1 mV zero-to-peak lock-in excitation).

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